

SEMiX[®] 5

Trench IGBT Modules

Engineering Sample SEMiX305GD07E4

Target Data

Features

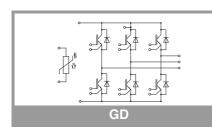
- Solderless assembly solution with PressFIT signal pins and screw power terminals
- IGBT 4 Trench Gate Technology
- V_{CE(sat)} with positive temperature coefficient
- Low inductance case
- Reliable mechanical design with injection moulded terminals and robust internal connections
- UL recognized file no. E63532
- NTC temperature sensor inside

Typical Applications*

- Three phase inverters for AC motor speed control
- UPS

Remarks

- Case temperature limited to T_C=125°C max.
- Product reliability results are valid for $T_{jop}{=}150^{\circ}C$
- Dynamic data are estimated
- For storage and case temperature with TIM see document "TP(HALA P8) SEMiX 5p"



Absolut	e Maximum Rati	ngs			
Symbol	Conditions		Values	Unit	
IGBT					
V _{CES}	T _j = 25 °C		650	V	
lc	T _j = 175 °C	T _c = 25 °C	372	А	
		T _c = 80 °C	281	Α	
I _{Cnom}			300	А	
I _{CRM}	I _{CRM} = 3xI _{Cnom}		900	Α	
V _{GES}			-20 20	V	
t _{psc}	$V_{CC} = 360 V$ $V_{GE} \le 15 V$ $V_{CES} \le 650 V$	T _j = 150 °C	10	μs	
Tj			-40 175	°C	
Inverse	diode				
V _{RRM}	T _j = 25 °C		650		
l _F	T _j = 175 °C	T _c = 25 °C	335	А	
		T _c = 80 °C	244	А	
I _{Fnom}			300	А	
I _{FRM}	$I_{FRM} = 2 x I_{Fnom}$		600	А	
I _{FSM}	t _p = 10 ms, sin 180°, T _j = 25 °C		2160		
Tj			-40 175	°C	
Module				•	
I _{t(RMS)}			400	А	
T _{stg}	module without	TIM	-40 125	°C	
V _{isol}	AC sinus 50Hz,	t = 1 min	4000	V	

Characteristics Symbol Conditions Unit min. typ. max. IGBT I_C = 300 A T_i = 25 °C V V_{CE(sat)} 1.55 1.95 V_{GE} = 15 V T_i = 150 °C 2.15 V 1.75 chiplevel V_{CE0} T_i = 25 °C 0.9 1 V chiplevel T_i = 150 °C 0.82 0.9 v T_i = 25 °C 2.2 3.2 mΩ V_{GE} = 15 V r_{CE} chiplevel T_i = 150 °C 3.1 4.2 mΩ V_{GE(th)} V 5.1 $V_{GE}=V_{CE}$, $I_C = 8 \text{ mA}$ 5.8 6.4 ICES V_{GE} = 0 V, V_{CE} = 650 V, T_i = 25 °C 0.2 mΑ f = 1 MHz Cies 18.5 nF V_{CE} = 25 V Coes f = 1 MHz1.16 nF $V_{GE} = 0 V$ f = 1 MHz 0.55 nF Cres Q_G V_{GE} = - 15 V...+ 15 V 3023 nC T_i = 25 °C 1.0 R_{Gint} Ω V_{CC} = 300 V T_i = 150 °C t_{d(on)} ns $I_{\rm C} = 300 \, {\rm A}$ T_i = 150 °C tr ns V_{GE} = +15/-15 V Eon T_j = 150 °C 5.5 m.J $R_{G \text{ on}} = 2 \Omega$ T_i = 150 °C ns t_{d(off)} $R_{G off} = 2 \Omega$ $di/dt_{on} = 4760 \text{ A}/\mu \text{s} T_{i} = 150 \text{ }^{\circ}\text{C}$ tf ns di/dt_{off} = 3478 A/µs T_i = 150 °C 15.6 $\mathsf{E}_{\mathsf{off}}$ mJ $R_{th(j-c)}$ per IGBT 0.16 K/W per IGBT (λgrease=0.81 W/mK, $R_{\text{th(c-s)}}$ 0.051 K/W thickness 50-100µm) 0.031 K/W per IGBT (λ=3.4 W/mK) R_{th(c-s)}



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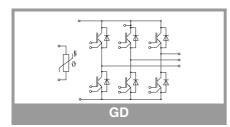
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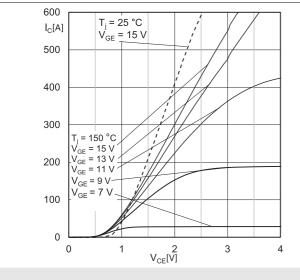
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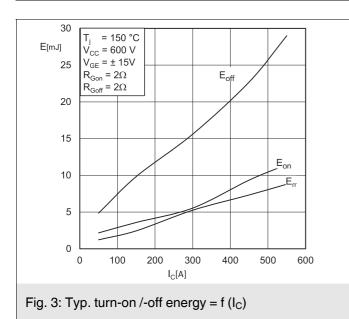
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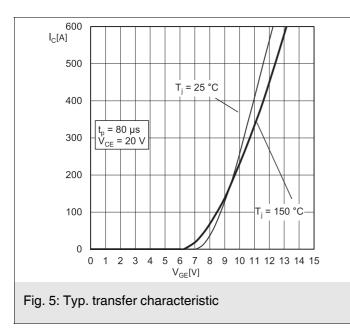
Characte	ristics					
Symbol	Conditions	min.	typ.	max.	Unit	
Inverse d	iode					
$V_F = V_{EC}$	I _F = 300 A	T _j = 25 °C		1.40	1.76	V
	V _{GE} = 0 V chiplevel	T _j = 150 °C		1.39	1.77	V
V _{F0}	chiplevel	T _j = 25 °C		1.04	1.24	V
		T _j = 150 °C		0.85	0.99	V
r _F	chiplevel	T _j = 25 °C		1.19	1.76	mΩ
		T _j = 150 °C		1.79	2.6	mΩ
I _{RRM}	I _F = 300 A	T _j = 150 °C		212		Α
Q _{rr}	di/dt _{off} = 4760 A/µs V _{GE} = -15 V	T _j = 150 °C		21.6		μC
E _{rr}	$V_{GE} = -13 V$ $V_{CC} = 300 V$	T _j = 150 °C		5.2		mJ
R _{th(j-c)}	per diode				0.25	K/W
R _{th(c-s)}	per diode (λgrease thickness 50-100μr		0.047		K/W	
R _{th(c-s)}	per diode (λ=3.4 W		0.037		K/W	
Module	·					
L _{CE}			20		nH	
$R_{CC'+EE'}$	measured per switch	T _C = 25 °C		1.2		mΩ
		T _C = 125 °C		1.65		mΩ
Rth _{(c-s)1}	calculated without t		0.004		K/W	
Rth _{(c-s)2}	including thermal co Ts underneath mod (m*K))		0.0069		K/W	
Rth _{(c-s)2}	including thermal co Ts underneath moo phase change mate		0.0048		K/W	
Ms	to heat sink (M5)		3		6	Nm
Mt		to terminals (M6)	3		6	Nm
]					Nm
W				398		g
Temperat	ure Sensor					
R ₁₀₀	T _c =100°C (R ₂₅ =5 kΩ)			493 ± 5%		Ω
B _{100/125}	R _(T) =R ₁₀₀ exp[B _{100/1}		3550 ±2%		К	

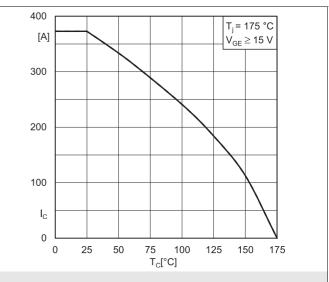


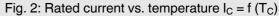


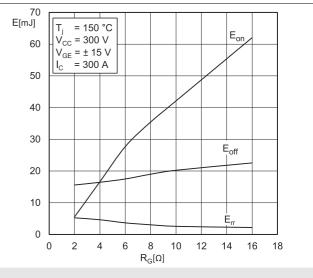


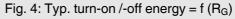


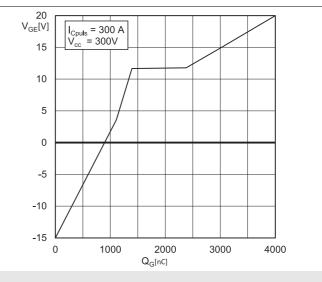


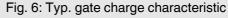


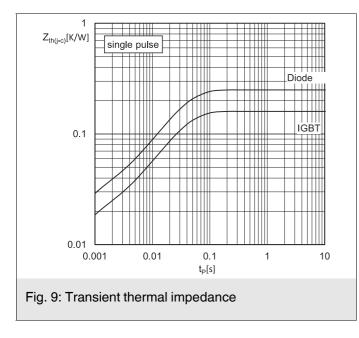


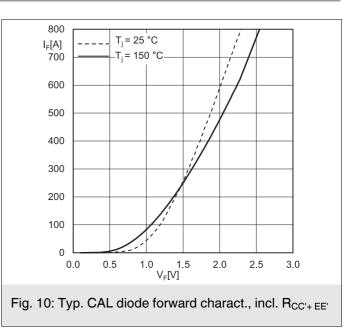


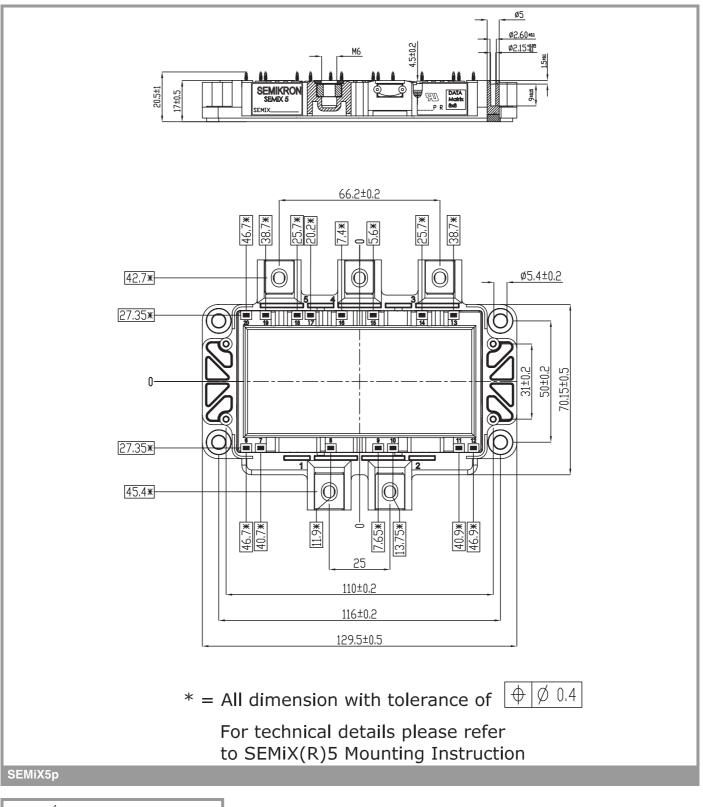


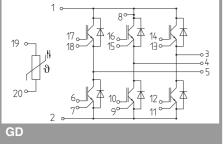












This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, chapter IX.

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